TECHNICAL DATA DATA SHEET 346, REV. A

HERMETIC ULTRAFAST RECOVERY RECTIFIER

DESCRIPTION: 300 VOLT, 15 AMP, 35 NS, RECTIFIER IN A HERMETIC TO-254 PACKAGE.

MAX RATINGS/ELECTRICAL CHARACTERISTICS ALL RATINGS ARE AT $T_A = 25 \circ$

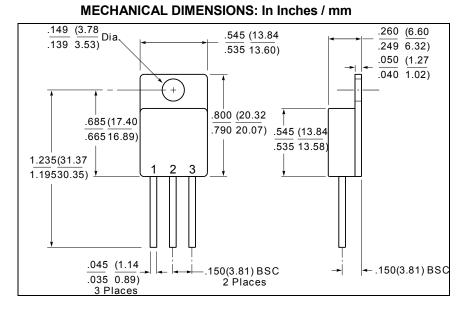
ALL RATINGS ARE AT T_A = 25 $^\circ C$ UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE (PER LEG)	PIV	300	Volts
MAXIMUM FORWARD VOLTAGE DROP (PER LEG)			
$I_{\rm F} = 10$ A, $T_{\rm A} = 25^{0}$ C	V _f	1.35	Volts
$I_{\rm F}$ = 20A, $T_{\rm A}$ = 25°C		1.55	
I _F = 10A, T _A = -55 ⁰ C		1.45	
MAXIMUM DC OUTPUT CURRENT ($T_c = 100^{\circ}C$) (PER LEG)	Ι _Ο	15	Amps
PEAK SINGLE CYCLE SURGE CURRENT t_p = 8.3 msec.		150	Amps
MAXIMUM REVERSE RECOVERY TIME ($I_f = 0.5A$, $I_r = 1.0A$, $I_{rr} = 0.25A$)	t _{rr}	35	nsec
MAXIMUM REVERSE CURRENT I _r @ PIV PER LEG $(T_c = 25^{\circ}C)$		50	μA
$(T_{\rm C} = 100^{\rm 0}{\rm C})$		5	mA
MAXIMUM THERMAL RESISTANCE (PER LEG)	R _{θJC}	2.0	°C /W
MAXIMUM OPERATING TEMPERATURE RANGE		-55 to +175	°C
JUNCTION CAPACITANCE V _R = 10Vdc, f = 1MHz	CJ	150	pF
V _{SIG} = 50mV (p-p) (Max)			

* Suffix R denotes common anode version.

SENSITRON SEMICONDUCTOR

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TO-254

TYPE	PIN 1	PIN 2	PIN 3
DUAL RECTIFIER, COMMON CATHODE	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (R)	CATHODE 1	COMMON ANODE	CATHODE 2

SCHEMATIC



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